Complementary Silicon Power Transistors

These complementary silicon power transistors are designed for high–speed switching applications, such as switching regulators and high frequency inverters. The devices are also well–suited for drivers for high power switching circuits.

- Fast Switching tf = 90 ns (Max)
- Key Parameters Specified @ 100°C
- Low Collector–Emitter Saturation Voltage VCE(sat) = 1.0 V (Max) @ 8.0 A
- Complementary Pairs Simplify Circuit Designs



15 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 80 VOLTS 83 WATTS



MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	VCEO	80	Vdc
Collector-Emitter Voltage	VCEV	100	Vdc
Emitter Base Voltage	V _{EB}	7.0	Vdc
Collector Current — Continuous — Peak (1)	IC ICM	15 20	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	PD	83 0.67	Watts W/°C
Operating and Storage Junction Temperature Range	TJ, T _{stg}	-55 to 150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction to Case	R _{θJC}	1.5	°C/W
Thermal Resistance, Junction to Ambient	R _{θJA}	62.5	°C/W
Maximum Lead Temperature for Soldering Purposes: 1/8" from Case for 5 Seconds	ΤL	275	°C

(1) Pulse Width \leq 6.0 ms, Duty Cycle \leq 50%.

NOTE: All polarities are shown for NPN transistors. For PNP transistors, reverse polarities.



D44VH D45VH

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

	Characteristic			Min	Тур	Max	Unit
OFF CHARACTERISTIC	cs						
Collector–Emitter Sust (I _C = 25 mAdc, I _B =	e e ()		VCEO(sus)	80	-	—	Vdc
	ff Current /, VBE(off) = 4.0 Vdc) /, VBE(off) = 4.0 Vdc, T _C = 100°C)		ICEV	_		10 100	μAdc
Emitter Base Cutoff Cu (V _{EB} = 7.0 Vdc, I _C =			IEBO	—	—	10	μAdc
ON CHARACTERISTIC	S (1)					-	_
DC Current Gain (I _C = 2.0 Adc, V _{CE} : (I _C = 4.0 Adc, V _{CE} :			hFE	35 20			-
Collector-Emitter Satu ($I_C = 8.0 \text{ Adc}, I_B = 0$ ($I_C = 8.0 \text{ Adc}, I_B = 0$ ($I_C = 15 \text{ Adc}, I_B = 3$	0.4 Adc) 0.8 Adc)	D44VH10 D45VH10 D44VH10 D45VH10	VCE(sat)	 	 	0.4 1.0 0.8 1.5	Vdc
	0.4 Adc)	D44VH10 D45VH10 D44VH10 D45VH10	V _{BE(sat)}	 	 	1.2 1.0 1.1 1.5	Vdc
DYNAMIC CHARACTE	RISTICS					-	
Current Gain Bandwidth Product (I _C = 0.1 Adc, V _{CE} = 10 Vdc, f = 20 MHz)		fΤ	—	50	—	MHz	
Output Capacitance D44VH10 (V _{CB} = 10 Vdc, I _C = 0, f _{test} = 1.0 MHz) D44VH10 D45VH10 D45VH10		C _{ob}		120 275	_	pF	
SWITCHING CHARACT	ERISTICS		-		_		
Delay Time			td		—	50	ns
Rise Time	$(V_{CC} = 20 \text{ Vdc}, I_C = 8.0 \text{ Adc}, I_{B1} = I_{B2} = 0.8 \text{ Adc})$		tr	_	-	250	1
Storage Time			t _s	_	—	700	1
							-1

tf

_

(1) Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%.

90

Fall Time

PACKAGE DIMENSIONS



D44VH D45VH

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